



SSCP5401GSG

Dual PNP Switching Transistor

➤ Features

VCB	VCE	VEB	IC
-160V	-150V	-5V	-200mA

➤ Description

This device is designed for general-purpose high-voltage amplifiers and gas discharge display drivers. It is ideal for medium power amplification and switching.

➤ Applications

- General-purpose high-voltage amplifiers
- Gas discharge display drivers
- Medium power amplification and switching

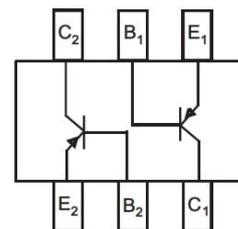
➤ Ordering Information

Device	Package	Shipping
SSCP5401GSG	SOT-363	3000/Reel

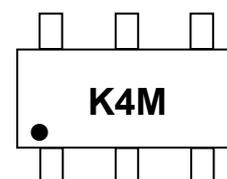
➤ Pin configuration



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Circuit Diagram



Marking (Top View)



➤ **Absolute Maximum Ratings**($T_A=25^{\circ}\text{C}$ unless otherwise noted)

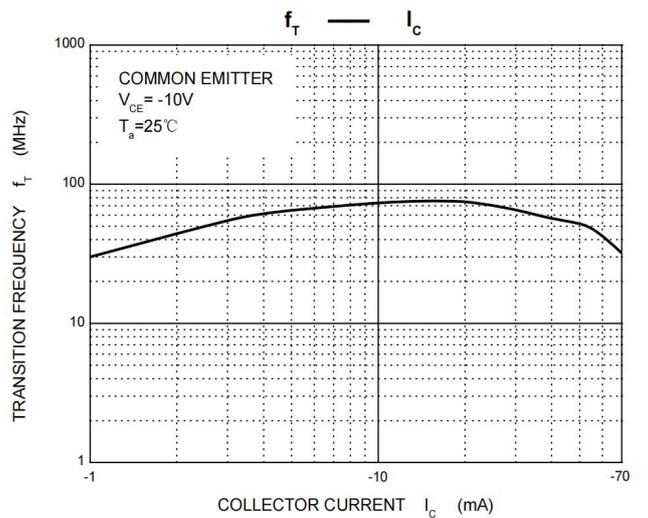
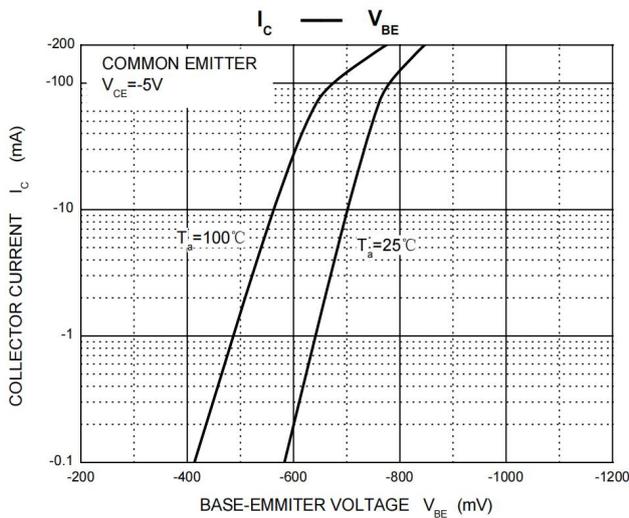
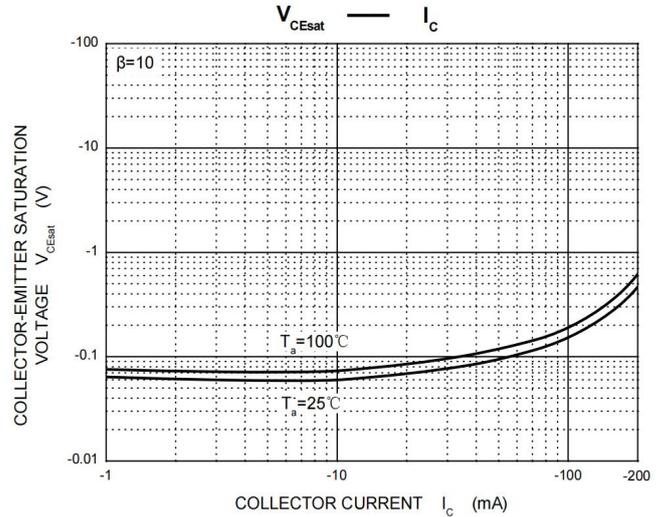
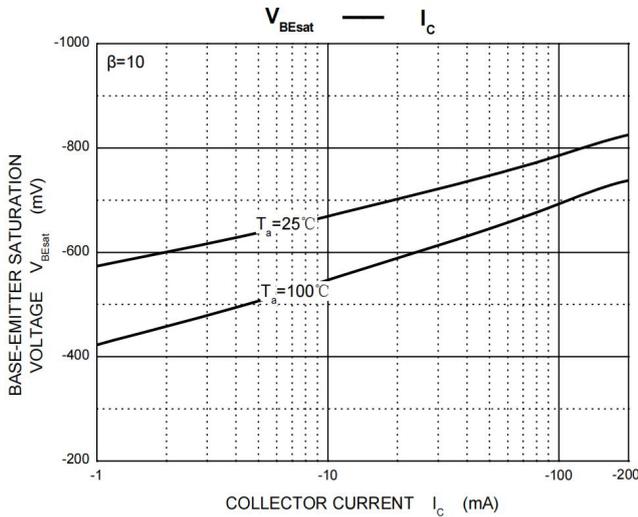
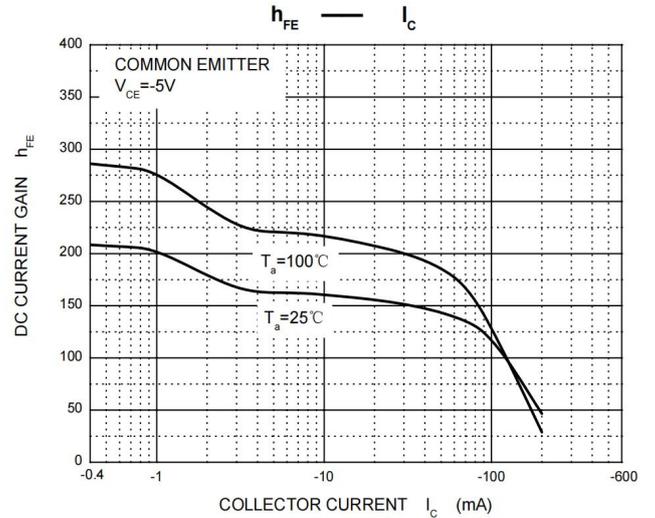
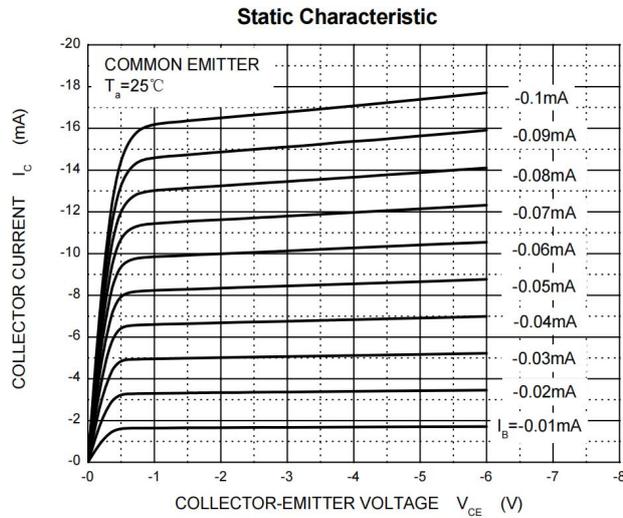
Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CB0}	-160	V
Collector- Emitter Voltage	V_{CE0}	-150	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current-Continuous	I_C	-200	mA
Collector Power Dissipation	P_C	200	mW
Junction Temperature	T_J	-55 to 150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55 to 150	$^{\circ}\text{C}$

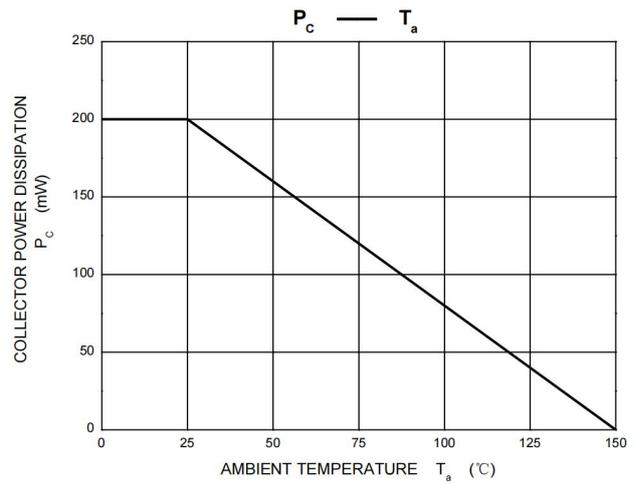
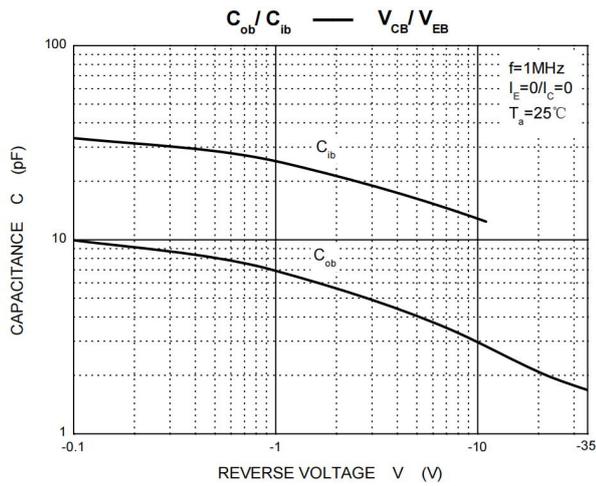
➤ **Electrical Characteristics** ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	BV_{CB0}	$I_C = -100\mu\text{A}, I_E = 0$	-160			V
Collector-emitter Breakdown Voltage	BV_{CE0}	$I_C = -1\text{mA}, I_B = 0$	-150			V
Emitter -Base Breakdown Voltage	BV_{EBO}	$I_E = -10\mu\text{A}, I_C = 0$	-5			V
Collector Cutoff Current	I_{CB0}	$V_{CB} = -120\text{V}, I_E = 0$			-50	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = -3\text{V}, I_C = 0$			-50	nA
DC Current Gain	h_{FE}	$V_{CE} = -5\text{V}, I_C = -1\text{mA}$	50			
		$V_{CE} = -5\text{V}, I_C = -10\text{mA}$	100		300	
		$V_{CE} = -5\text{V}, I_C = -50\text{mA}$	50			
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -10\text{mA}, I_B = -1\text{mA}$			-0.2	V
		$I_C = -50\text{mA}, I_B = -5\text{mA}$			-0.5	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -10\text{mA}, I_B = -1\text{mA}$			-1.0	V
		$I_C = -50\text{mA}, I_B = -5\text{mA}$			-1.0	V
Output Capacitance	C_{ob}	$V_{CB} = -10\text{V}, I_E = 0, f = 1\text{MHz}$			6	pF
Transition frequency	f_T	$V_{CE} = -10\text{V}, I_C = -10\text{mA}$ $f = 100\text{MHz}$	100			MHz



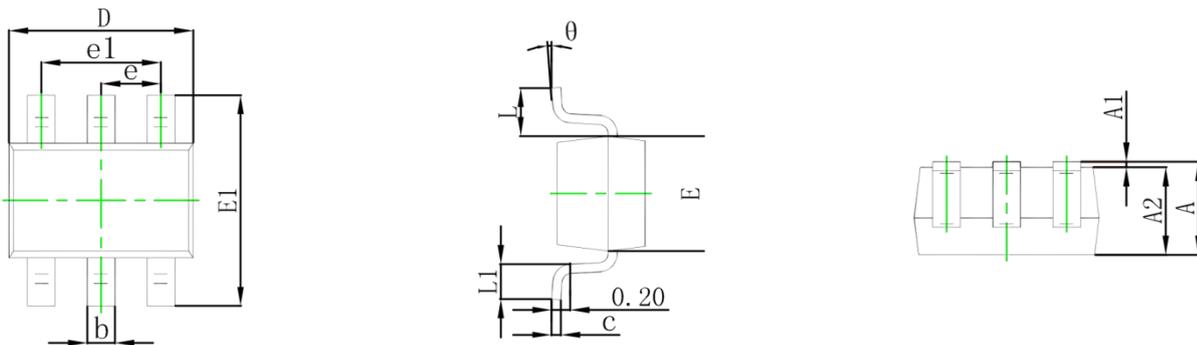
➤ **Typical Performance Characteristics (TA=25°C unless otherwise noted)**





➤ Package Information

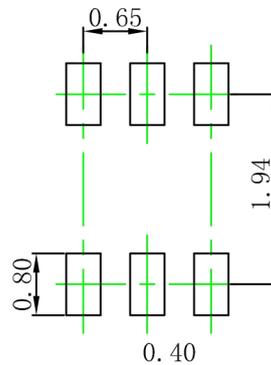
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Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.100	0.150	0.004	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.400	0.085	0.094
e	0.650 TYP		0.026 TYP	
e1	1.200	1.400	0.047	0.055
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
θ	0 $^\circ$	8 $^\circ$	0 $^\circ$	8 $^\circ$



➤ Recommended Pad outline(Unit: mm)



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